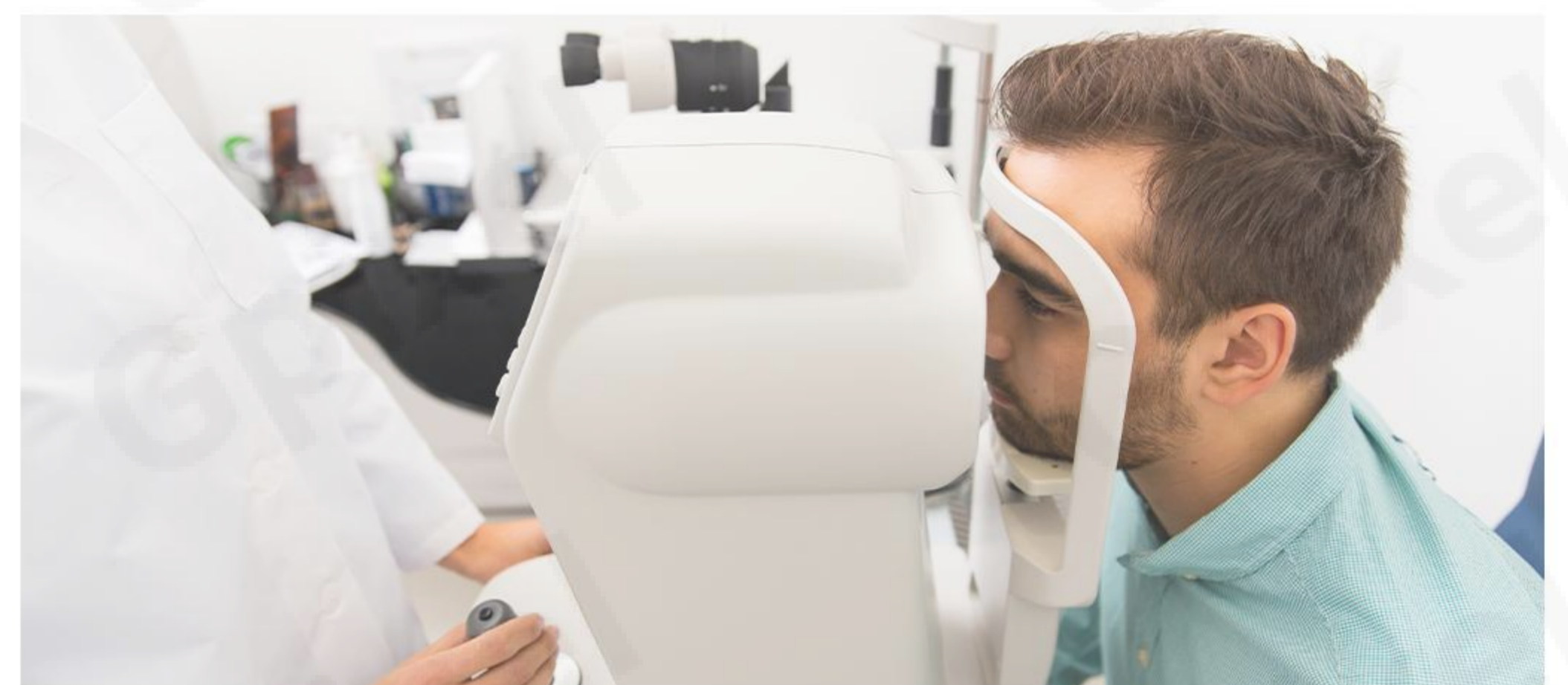


# GLR1002BSI-S

2K 10  $\mu\text{m}$  x 200  $\mu\text{m}$  PIXEL SIZE  
HIGH SPEED BSI LINE SCAN CMOS IMAGE SENSOR

The **GLR1002BSI-S** is a next generation 2K back side illuminated (BSI) CMOS line scan sensor designed to elevate performance in OCT and spectroscopy applications, combining high speed readout up to 250 kHz with a rectangular 10  $\times$  200  $\mu\text{m}$  pixel optimized for precise optical alignment. Its advanced BSI global shutter architecture delivers 58% QE at 850 nm, a 155 ke<sup>-</sup> full well capacity, low read noise, and true 12 /14 bit output, enabling wide dynamic range and high contrast fringe reconstruction. High line rates are supported through 1.2 GHz Sub-LVDS outputs with < 450 mW power consumption, providing an efficient balance of speed and system integration. Engineered for both high throughput imaging and demanding diagnostic workflows, the **GLR1002BSI-S** is housed in a robust ceramic CLCC package with a double sided AR coated glass lid and a compact 40 mm  $\times$  11 mm footprint, ensuring stable mechanical integration and excellent alignment in OCT optical paths.



## Key Features and Benefits

- ▶ Pixel Size: 10  $\mu\text{m}$  x 200  $\mu\text{m}$
- ▶ Fast Line Rate: 250 kHz
- ▶ High NIR QE
- ▶ 12 bit / 14 bit ADC

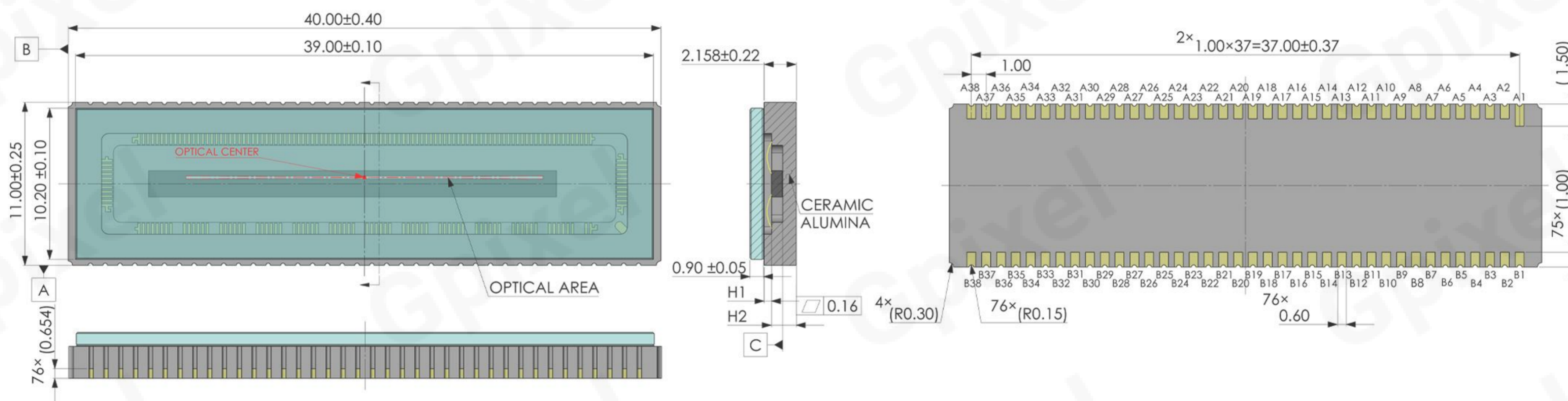
## Applications

- ▶ Optical Coherence Tomography (OCT)
- ▶ Non-Destructive Industrial Inspection
- ▶ In-Vivo Medical Endoscopy
- ▶ Spectroscopy

## Specifications

|                     |  |                   |  |
|---------------------|--|-------------------|--|
| Nr of Active Pixels | 2411 (H) x 1 (V)   | Optical Format    | 24.11 mm   |
| Pixel Size          | 10 μm x 200 μm   | Shutter Type      | Global Shutter   |
| Peak QE             | 91 % (440 nm)<br>58 % (850 nm)                             | Temporal Noise    | 33.2 e <sup>-</sup> (12 bit)<br>20 e <sup>-</sup> (14 bit) |
| Max. SNR            | 51.9 dB  | Dynamic Range     | 73.4 dB (12 bit)<br>77.6 dB (14 bit)                       |
| Max Line Rate       | 250/130 kHz (12 bit)<br>100 kHz (14 bit)                   | Dark Current      | T.B.D  |
| Output Format       | 7x Sub-LVDS  | Max. Data Rate    | 8.4 Gbps   |
| Chroma              | Mono   | Power Consumption | < 450 mW   |
| Supply Voltage      | 3.6 V for analog<br>1.5 V for digital<br>1.8 V-3.3V for IO | Package           | 76 x lead CLCC<br>(40 mm x 11 mm)                          |

## Package Drawing



## Contact Gpixel

### GPIXEL CHINA CHANGCHUN (HQ)

Office Buildings 1 and 5, Phase I, Optoelectronic Information Industrial Park, No. 7691 Ziyou Road, Changchun, Jilin, China.  
Phone: +86-431-85077785

### GPIXEL EUROPE

Gpixel NV  
Copernicuslaan 60, 2018 Antwerpen, Belgium  
Phone: +32-33034442

### GPIXEL JAPAN

Gpixel Japan Co., Ltd.  
TOC Osaki Building 18th Floor, 1-6-1 Osaki, Shinagawa-ku, Tokyo, 141-0032 Japan  
Phone: +81-03-5962-1600



Disclaimer: The product information and pictures in this flyer are for reference only. For the latest information please visit [www.gpixel.com](http://www.gpixel.com).  
GP-PR260401 V1.0